

View Online at <https://aerobasegroup.com/nsn/5961-01-141-5672>

Inclosure Material:

Ceramic

Overall Length:

0.785 inches

Terminal Length:

0.120 inches

Overall Height:

0.280 inches

Overall Width:

0.300 inches

Mounting Facility Quantity:

14

Component Name And Quantity:

4 semiconductor device diode

Mounting Method:

Terminal

Semiconductor Material:

Silicon all semiconductor

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-emitter, base open all semiconductor and 40.0 working peak off-state voltage all semiconductor

Current Rating Per Characteristic:

0.50 milliamperes source cutoff current of standard range all semiconductor

Power Rating Per Characteristic:

1900.0 milliwatts small-signal input power, common-emitter absolute all semiconductor

Maximum Operating Temperature Per Measurement Point:

-65.0 degrees celsius case and 175.0 degrees celsius case

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

14 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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